ESD Protection Device

RLDSON8Q252LC

Description

The RLDSON8Q252LC is a low capacitance high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The RLDSON8Q252LC complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a 8-pin DFN2010-8 lead-free package. Each device will protect two line pairs high-speed lines. The combination of small size, low capacitance, and high surge capability makes them ideal for use in applications such as Gigabit Ethernet, telecommunication lines, and LVDS interfaces.

Features

I Stand-off voltage: 2.5V Max.
I Ultra low leakage: nA level
I Operating voltage: 2.5V
I Ultra low clamping voltage
I Protects up to eight lines

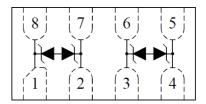
Complies with following standards: IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

IEC61000-4-5 (Lightning) 20A (8/20µs)

I RoHS Compliant

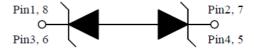
Pin Configuration



Circuit Diagram

Applications

- I HDBaseT Protector
- I LVDS Interfaces
- I 10/100/1000 Ethernet
- I Notebooks, Desktops, Servers
- I Networking Equipment
- I Switching Systems
- I Audio/Video Inputs



Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp =8/20μs)	P _{PP}	350	W
ESD Voltage (Air) ESD Voltage (Contact)	V _{ESD}	±30 ±30	kV
Operating Temperature	T _{OPT}	-45 to +85	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Electrical Characteristics (@ 25°C Unless Otherwise Specified)

Type Number	Reverse Stand-Off Voltage	Minimum Breakdown Voltage	Peak Pulse Voltage @8/20µS	V _c @8/20μs		Reverse Leakage @V _{RWM}	Max. Capacitance
	V _{RWM}	V _{BR} @1mA	V _c @1A	(max.)	@I _{PP}	I _R @V _{RWM}	C _J @ V _R =2.5V, f=1MHz
	V	V	V	٧	Α	μΑ	pF
RLDSON8Q252LC	2.5	4.0	7.0	18	20	0.05	0.8

Revised: 2021-11-02





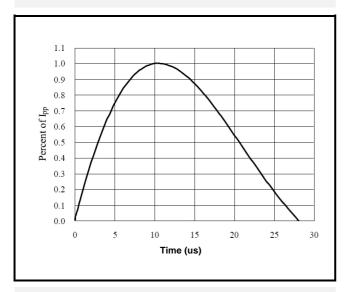
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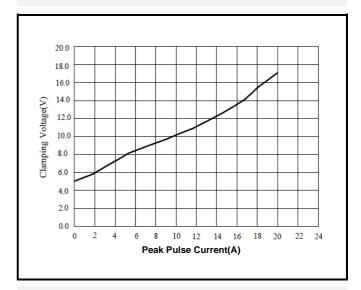
RLDSON8Q252LC

Typical Performance Characteristics (T_A=25[°]C unless otherwise Specified)

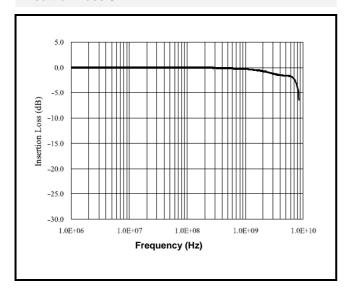
8/20 s Pulse Waveform



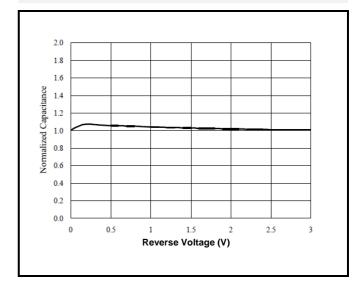
Clamping Voltage V_C vs. Current I_{PP}



Insertion Loss S21



Normalized Capacitance vs. Voltage





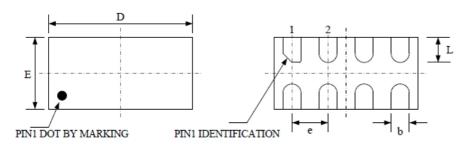


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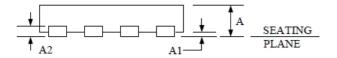
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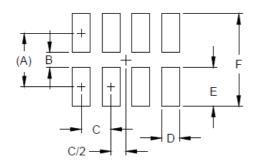
Dimensions



DIM	Millimeters				
DIN	Min	Тур	Max		
Α	0.37	0.40	0.43		
A1	0.000	0.02	0.05		
A2	0.13				
b	0.20	0.25	0.30		
D	1.90	2.00	2.10		
E	0.90	1.00	1.10		
е	0.50BSC				
L	0.30	0.35	0.40		
R	0.05	0.10	0.15		



Footprint



DIM	Millimeters	
Α	0.90	
В	0.25	
С	0.50	
D	0.30	
E	0.65	
F	1.55	